

Description

The TSV63x and TSV63xA series of dual and quad operational amplifiers offers low voltage operation and rail-to-rail input and output.

This family features an excellent speed/power consumption ratio, offering an 880 kHz gain-bandwidth product while consuming only 60 μ A at 5 V supply voltage.

These features make the TSV63x and TSV63xA family ideal for sensor interfaces, battery-supplied and portable applications, and active filtering.

Applications

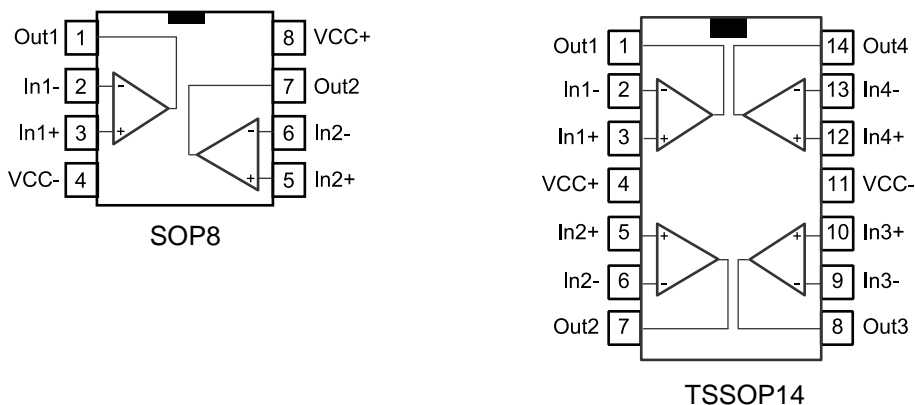
- Battery-powered applications
- Portable devices
- Signal conditioning
- Active filtering
- Medical instrumentation

Features

- Rail-to-rail input and output
- Low power consumption: 60 μ A typ at 5 V
- Low supply voltage: 1.5 V - 5.5 V
- Gain bandwidth product: 880 kHz typ
- Unity gain stable on 100 pF capacitor
- Low power shutdown mode: 5 nA typ
- Low offset voltage: 800 μ V max (A version)
- Low input bias current: 1 pA typ
- EMI hardened op amps
- Automotive qualification

Package pin connections

Figure 1: Pin connections for each package (top view)



Absolute maximum ratings and operating conditions

Table 2: Absolute maximum ratings (AMR)

Symbol	Parameter	Value	Unit	
V_{CC}	Supply voltage	6	V	
V_{id}	Differential input voltage	$\pm V_{CC}$		
V_{in}	Input voltage	$(V_{CC-}) - 0.2$ to $(V_{CC+}) + 0.2$		
I_{in}	Input current	10	mA	
\overline{SHDN} SHDN	Shutdown voltage	$(V_{CC-}) - 0.2$ to $(V_{CC+}) + 0.2$	V	
T_{stg}	Storage temperature	-65 to 150	$^{\circ}$ C	
R_{thja}	Thermal resistance junction to ambient	SOP8	125	$^{\circ}$ C/W
		TSSOP14	100	
T_j	Maximum junction temperature	150	$^{\circ}$ C	
ESD	HBM: human body model	4000	V	
	MM: machine model	300		
	CDM: charged device model	1500		
	Latch-up immunity	200	mA	

Notes:

- (1) All voltage values, except the differential voltage are with respect to the network ground terminal.
- (2) Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- (3) $V_{CC} - V_{IN}$ must not exceed 6 V, V_{IN} must not exceed 6 V.
- (4) Input current must be limited by a resistor in series with the inputs
- (5) R_{th} are typical values
- (6) Short-circuits can cause excessive heating and destructive dissipation
- (7) Human body model: 100 pF discharged through a 1.5 k Ω resistor between two pins of the device, done for all couples of pin combinations with other pins floating.
- (8) Machine model: a 200 pF cap is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω), done for all couples of pin combinations with other pins floating
- (9) Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to the ground.

Table 3: Operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	1.5 to 5.5	V
V _{ICM}	Common-mode input voltage range	(V _{CC-}) - 0.1 to (V _{CC+}) + 0.1	
T _{oper}	Operating free-air temperature range	-40 to 125	°C

Electrical characteristics

Table 4: Electrical characteristics at VCC+ = 1.8 V with VCC- = 0 V, Vicm = VCC/2, Tamb = 25° C, and RL connected to VCC/2 (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
DC performance						
V _{io}	Offset voltage	TSV63x			3	mV
		TSV63xA			0.8	
		T _{min} < T _{op} < T _{max} - TSV63x			4.5	
		T _{min} < T _{op} < T _{max} - TSV63xA			2	
$\Delta V_{io}/\Delta T$	Input offset voltage drift			2		μ V/°C
I _{io}	Input offset current	(V _{out} = V _{CC} /2)		1	10	pA
		T _{min} < T _{op} < T _{max}		1	100	
I _{ib}	Input bias current	(V _{out} = V _{CC} /2)		1	10	pA
		T _{min} < T _{op} < T _{max}		1	100	
CMR	Common mode rejection ratio 20 log ($\Delta V_{io}/\Delta V_{ic}$)	0 V to 1.8 V, V _{out} = 0.9 V	53	74		dB
		T _{min} < T _{op} < T _{max}	51			
A _{vd}	Large signal voltage gain	R _L = 10 k Ω , V _{out} = 0.5 V to 1.3 V	85	95		dB
		T _{min} < T _{op} < T _{max}	80			
V _{OH}	High level output voltage, (V _{OH} = V _{CC} - V _{out})	R _L = 10 k Ω		5	35	mV
		T _{min} < T _{op} < T _{max}			50	
V _{OL}	Low level output voltage	R _L = 10 k Ω		4	35	mV
		T _{min} < T _{op} < T _{max}			50	
I _{out}	I _{sink}	V _o = 1.8 V	6	12		mA
		T _{min} < T _{op} < T _{max}	4			
	I _{source}	V _o = 0 V	6	10		
		T _{min} < T _{op} < T _{max}	4			
I _{CC}	Supply current (per channel)	No load, V _{out} = V _{CC} /2	40	50	60	μ A
		T _{min} < T _{op} < T _{max}			62	
AC performance						
GBP	Gain bandwidth product	R _L = 2 k Ω , C _L = 100 pF, f = 100 kHz	700	790		kHz
ϕ_m	Phase margin	R _L = 2 k Ω , C _L = 100 pF		45		Degrees
G _m	Gain margin	R _L = 2 k Ω , C _L = 100 pF		13		dB
SR	Slew rate	R _L = 2 k Ω , C _L = 100 pF, A _v = 1	0.2	0.27		V/ μ s
e _n	Equivalent input noise voltage	f = 1 kHz		60		nV/ \sqrt Hz
		f = 10 kHz		33		

Table 5: Shutdown characteristics VCC = 1.8 V

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
DC performance						
I_{CC}	Supply current in shutdown mode (all channels)	$\overline{\text{SHDN}} = V_{CC-}$		2.5	50	nA
		$T_{\min} < T_{op} < 85^{\circ} \text{C}$			200	
		$T_{\min} < T_{op} < 125^{\circ} \text{C}$			1.5	μA
t_{on}	Amplifier turn-on time	$R_L = 2 \text{ k}\Omega$, $V_{out} = (V_{CC-})$ to $(V_{CC-}) + 0.2 \text{ V}$		200		ns
t_{off}	Amplifier turn-off time	$R_L = 2 \text{ k}\Omega$, $V_{out} = (V_{CC+}) - 0.5 \text{ V}$ to $(V_{CC+}) - 0.7 \text{ V}$		20		
V_{IH}	$\overline{\text{SHDN}}$ logic high		1.35			V
V_{IL}	$\overline{\text{SHDN}}$ logic low				0.6	
I_{IH}	$\overline{\text{SHDN}}$ current high	$\overline{\text{SHDN}} = V_{CC+}$		10		pA
I_{IL}	$\overline{\text{SHDN}}$ current low	$\overline{\text{SHDN}} = V_{CC-}$		10		
I_{OLeak}	Output leakage in shutdown mode	$\overline{\text{SHDN}} = V_{CC-}$		50		
		$T_{\min} < T_{op} < 125^{\circ} \text{C}$		1		nA

Dual and quad, rail-to-rail input/output, 60 μ A, 880 kHz operational amplifiers

Table 6: $V_{CC+} = 3.3$ V, $V_{CC-} = 0$ V, $V_{icm} = V_{CC}/2$, $T_{amb} = 25^\circ$ C, R_L connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
DC performance						
V_{io}	Offset voltage	TSV63x			3	mV
		TSV63xA			0.8	
		$T_{min} < T_{op} < T_{max}$ - TSV63x			4.5	
		$T_{min} < T_{op} < T_{max}$ - TSV63xA			2	
$\Delta V_{io}/\Delta T$	Input offset voltage drift			2		μ V/ $^\circ$ C
I_{io}	Input offset current	$V_{out} = V_{CC}/2$		1	10 ⁽¹⁾	pA
		$T_{min} < T_{op} < T_{max}$		1	100	
I_{ib}	Input bias current	$V_{out} = V_{CC}/2$		1	10 ⁽¹⁾	pA
		$T_{min} < T_{op} < T_{max}$		1	100	
CMR	Common mode rejection ratio $20 \log (\Delta V_{ic}/\Delta V_{io})$	0 V to 3.3 V, $V_{out} = 1.65$ V	57	79		dB
		$T_{min} < T_{op} < T_{max}$	53			
A_{vd}	Large signal voltage gain	$R_L = 10$ k Ω , $V_{out} = 0.5$ V to 2.8 V	88	98		dB
		$T_{min} < T_{op} < T_{max}$	83			
V_{OH}	High level output voltage, ($V_{OH} = V_{CC} - V_{out}$)	$R_L = 10$ k Ω		5	35	mV
		$T_{min} < T_{op} < T_{max}$			50	
V_{OL}	Low level output voltage	$R_L = 10$ k Ω		4	35	mV
		$T_{min} < T_{op} < T_{max}$			50	
I_{out}	I_{sink}	$V_o = 3.3$ V	23	45		mA
		$T_{min} < T_{op} < T_{max}$	20			
	I_{source}	$V_o = 0$ V	23	38		
		$T_{min} < T_{op} < T_{max}$	20			
I_{CC}	Supply current, (per channel)	No load, $V_{out} = 1.75$ V	43	55	64	μ A
		$T_{min} < T_{op} < T_{max}$			66	
AC performance						
GBP	Gain bandwidth product	$R_L = 2$ k Ω , $C_L = 100$ pF, $f = 100$ kHz	710	860		kHz
ϕ_m	Phase margin	$R_L = 2$ k Ω , $C_L = 100$ pF		46		Degrees
G_m	Gain margin	$R_L = 2$ k Ω , $C_L = 100$ pF		13		dB
SR	Slew rate	$R_L = 2$ k Ω , $C_L = 100$ pF, $A_V = 1$	0.22	0.29		V/ μ s

Dual and quad, rail-to-rail input/output, 60 μ A, 880 kHz operational amplifiers

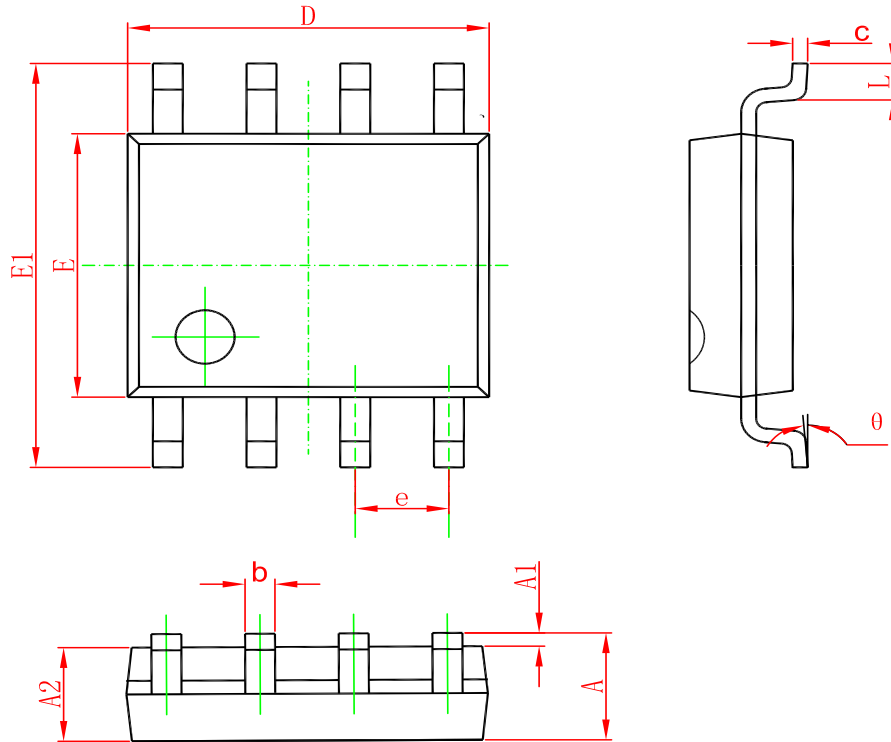
Table 7: Electrical characteristics at $V_{CC+} = 5$ V with $V_{CC-} = 0$ V, $V_{icm} = V_{CC}/2$, $T_{amb} = 25^\circ$ C, and R_L connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
DC performance						
V_{io}	Offset voltages	TSV63x			3	mV
		TSV63xA			0.8	
		$T_{min} < T_{op} < T_{max}$ - TSV63x			4.5	
		$T_{min} < T_{op} < T_{max}$ - TSV63xA			2	
$\Delta V_{io}/\Delta T$	Input offset voltage drift			2		μ V/ $^\circ$ C
I_{io}	Input offset current	$(V_{out} = V_{CC}/2)$		1	10 ⁽¹⁾	pA
		$T_{min} < T_{op} < T_{max}$		1	100	
I_{ib}	Input bias current	$(V_{out} = V_{CC}/2)$		1	10 ⁽¹⁾	pA
		$T_{min} < T_{op} < T_{max}$		1	100	
CMR	Common mode rejection ratio 20 log ($\Delta V_{ic}/\Delta V_{io}$)	0 V to 5 V, $V_{out} = 2.5$ V	60	80		dB
		$T_{min} < T_{op} < T_{max}$	55			
SVR	Supply voltage rejection ratio 20 log ($\Delta V_{CC}/\Delta V_{io}$)	$V_{CC} = 1.8$ to 5 V	75	102		dB
		$T_{min} < T_{op} < T_{max}$	73			
A_{vd}	Large signal voltage gain	$R_L = 10$ k Ω , $V_{out} = 0.5$ V to 4.5 V	89	98		dB
		$T_{min} < T_{op} < T_{max}$	84			
EMIRR	EMI rejection ratio, EMIRR = -20 log ($V_{RFpeak}/\Delta V_{io}$)	$V_{RF} = 100$ mV _{rms} , $f = 400$ MHz		61		dB
		$V_{RF} = 100$ mV _{rms} , $f = 900$ MHz		85		
		$V_{RF} = 100$ mV _{rms} , $f = 1800$ MHz		92		
		$V_{RF} = 100$ mV _{rms} , $f = 2400$ MHz		83		
V_{OH}	High level output voltage, ($V_{OH} = V_{CC} - V_{out}$)	$R_L = 10$ k Ω		7	35	mV
		$T_{min} < T_{op} < T_{max}$			50	
V_{OL}	Low level output voltage	$R_L = 10$ k Ω		6	35	mV
		$T_{min} < T_{op} < T_{max}$			50	
I_{out}	I_{sink}	$V_o = 5$ V	40	69		mA
		$T_{min} < T_{op} < T_{max}$	35			
	I_{source}	$V_o = 0$ V	40	74		
		$T_{min} < T_{op} < T_{max}$	35			
I_{CC}	Supply current, (per channel)	No load, $V_{out} = V_{CC}/2$	50	60	69	μ A
		$T_{min} < T_{op} < T_{max}$			72	
AC performance						
GBP	Gain bandwidth product	$R_L = 2$ k Ω , $C_L = 100$ pF, $f = 100$ kHz	730	880		kHz
F_u	Unity gain frequency	$R_L = 2$ k Ω , $C_L = 100$ pF		830		
ϕ_m	Phase margin	$R_L = 2$ k Ω , $C_L = 100$ pF		48		Degrees

Electrical characteristics

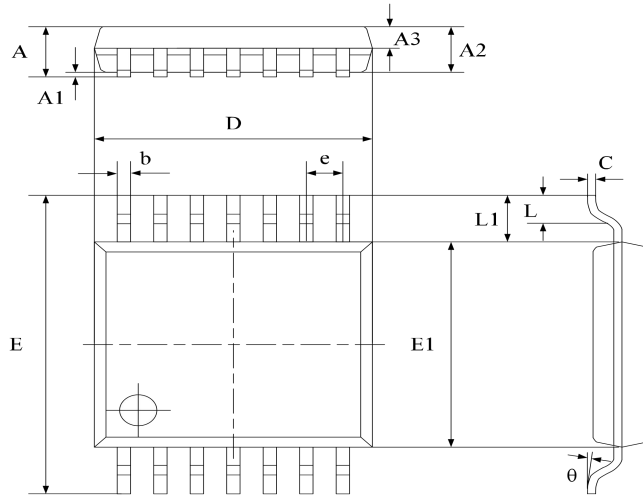
Package Dimension

SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
theta	0°	8°	0°	8°

TSSOP-14



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	-	1.200	-	0.0472
A1	0.050	0.150	0.002	0.006
A2	0.900	1.050	0.037	0.043
A3	0.390	0.490	0.016	0.020
b	0.200	0.290	0.008	0.012
C	0.130	0.180	0.005	0.007
D	4.860	5.060	0.198	0.207
E	6.200	6.600	0.253	0.269
E1	4.300	4.500	0.176	0.184
e	0.650 typ.		0.0256 typ.	
L1	1.000 ref.		0.0393 ref.	
L	0.450	0.750	0.018	0.031
θ	0°	8°	0°	8°

Ordering information

Order code	Package	Baseqty	Deliverymode	Marking
UMW TSV632IDT	SOP-8	2500	Tape and reel	TSV632
UMW TSV632AIDT	SOP-8	2500	Tape and reel	TSV632A
UMW TSV634IPT	TSSOP-14	4000	Tape and reel	TSV634

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[AZV358MMTR-G1](#) [SCY33178DR2G](#) [NCV20034DR2G](#) [NTE778S](#) [NTE871](#) [NTE937](#) [NJU7057RB1-TE2](#) [SCY6358ADR2G](#)
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